To our customers,

Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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H5N2512FN

Silicon N Channel MOS FET
High Speed Power Switching

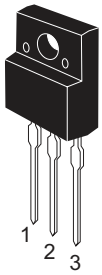
REJ03G1767-0100
Rev.1.00
Jul 02, 2009

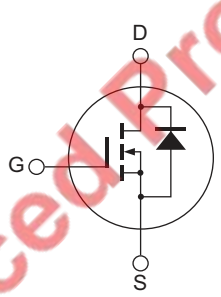
Features

- Low on-resistance
- Low leakage current
- High speed switching
- Built-in fast recovery diode

Outline

RENESAS Package code: PRSS0003AB-A
(Package name: TO-220FN)





1. Gate
2. Drain
3. Source

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	250	V
Gate to source voltage	V_{GSS}	±30	V
Drain current	I_D	18	A
Drain peak current	$I_{D\ (pulse)}$ Note1	72	A
Body-drain diode reverse drain current	I_{DR}	18	A
Body-drain diode reverse drain peak current	$I_{DR\ (pulse)}$ Note1	72	A
Avalanche current	I_{AP} Note3	18	A
Channel dissipation	Pch Note2	35	W
Channel to case thermal impedance	θch-c	3.57	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	–55 to +150	°C

Notes: 1. PW ≤ 10 ∝s, duty cycle ≤ 1%
2. Value at Tc = 25°C
3. Tch ≤ 150°C

Electrical Characteristics

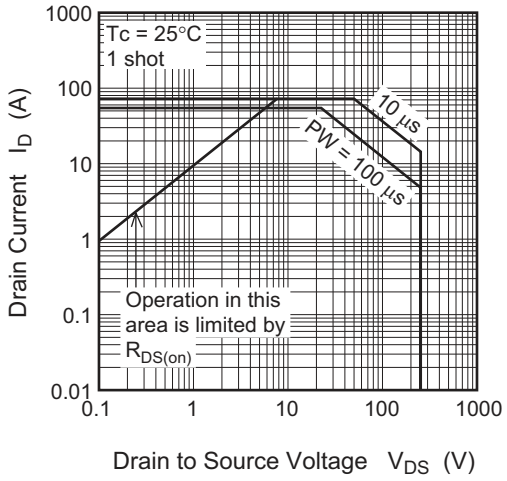
(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to Source breakdown voltage	$V_{(BR)DSS}$	250	—	—	V	I_D = 10 mA, V_{GS} = 0
Zero gate voltage drain current	I_{DSS}	—	—	10	∝A	V_{DS} = 250 V, V_{GS} = 0
Gate to source leak current	I_{GSS}	—	—	±0.1	∝A	V_{GS} = ±30 V, V_{DS} = 0
Gate to source cutoff voltage	$V_{GS(off)}$	1.5	—	4.0	V	V_{DS} = 10 V, I_D = 1 mA
Forward transfer admittance	$\|y_{fs}\|$	9	16	—	S	I_D = 9 A, V_{DS} = 10 V Note4
Static drain to source on state resistance	$R_{DS(on)}$	—	0.082	0.105	Ω	I_D = 9 A, V_{GS} = 10 V Note4
Input capacitance	Ciss	—	2200	—	pF	V_{DS} = 25 V V_{GS} = 0, f = 1 MHz
Output capacitance	Coss	—	300	—	pF	
Reverse transfer capacitance	Crss	—	85	—	pF	
Turn-on delay time	$t_{d(on)}$	—	32	—	ns	I_D = 9 A V_{GS} = 10 V R_L = 13.9 Ω Rg = 10 Ω
Rise time	t_r	—	60	—	ns	
Turn-off delay time	$t_{d(off)}$	—	160	—	ns	
Fall time	t_f	—	60	—	ns	
Total gate charge	Qg	—	81	—	nC	V_{DD} = 200 V V_{GS} = 10 V I_D = 18 A
Gate to source charge	Qgs	—	10	—	nC	
Gate to drain charge	Qgd	—	38	—	nC	
Body-drain diode forward voltage	V_{DF}	—	0.9	1.4	V	I_F = 18 A, V_{GS} = 0 Note4
Body-drain diode reverse recovery time	t_{rr}	—	110	—	ns	I_F = 18 A, V_{GS} = 0 diF/dt = 100 A/∝s
Body-drain diode reverse recovery time	Qrr	—	0.39	—	∝C	

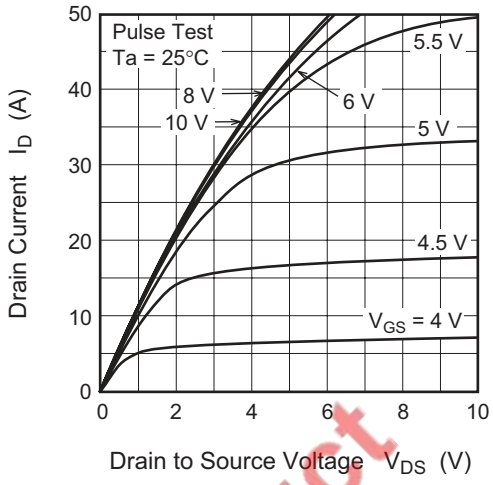
Notes: 4. Pulse test

Main Characteristics

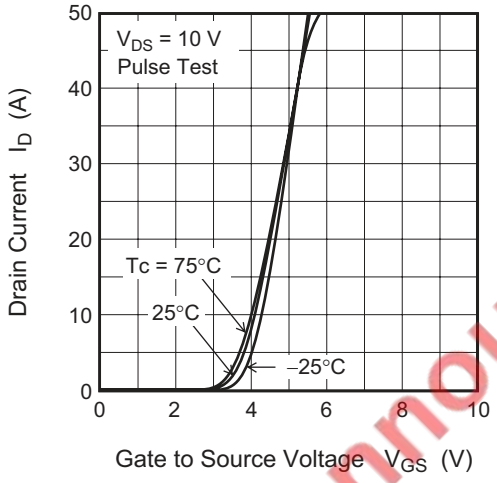
Maximum Safe Operation Area



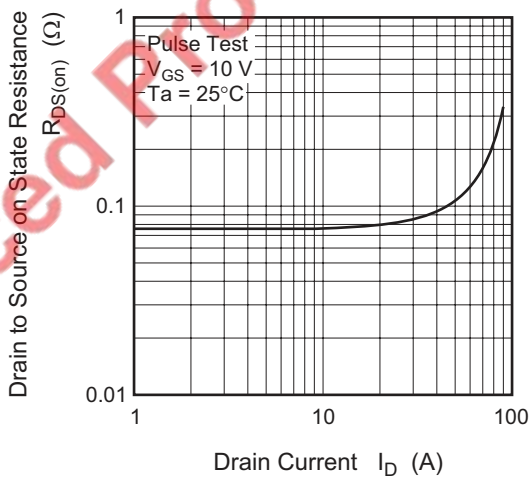
Typical Output Characteristics



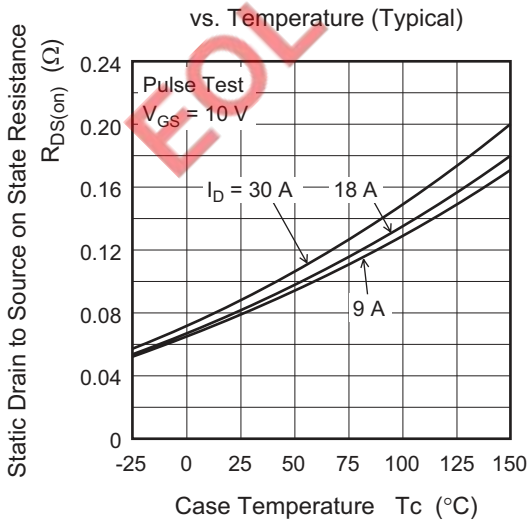
Typical Transfer Characteristics



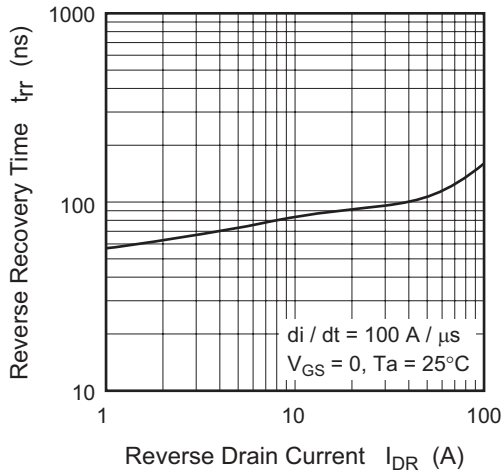
Static Drain to Source on State Resistance vs. Drain Current (Typical)



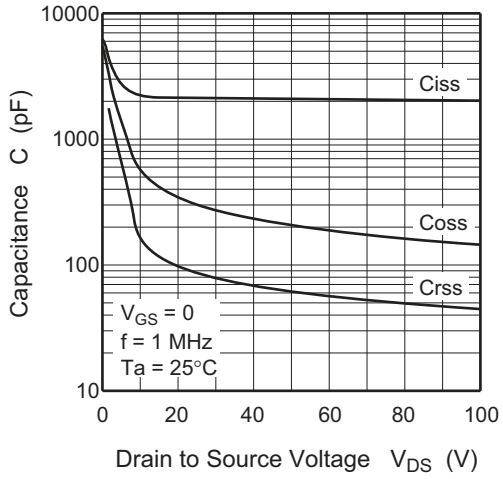
Static Drain to Source on State Resistance vs. Temperature (Typical)



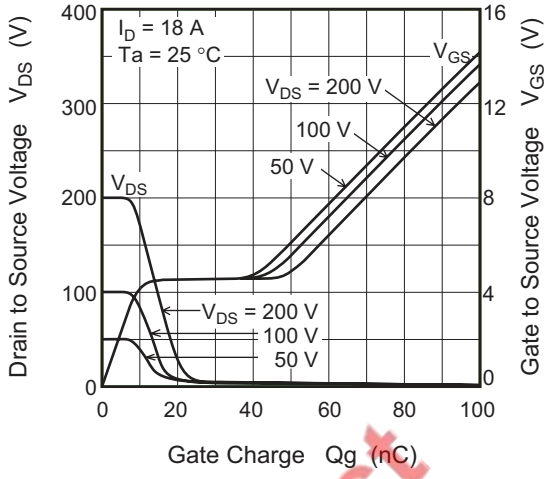
Body-Drain Diode Reverse Recovery Time (Typical)



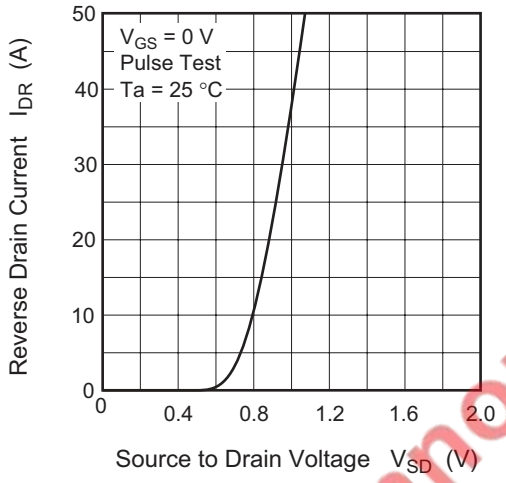
Typical Capacitance vs.
Drain to Source Voltage



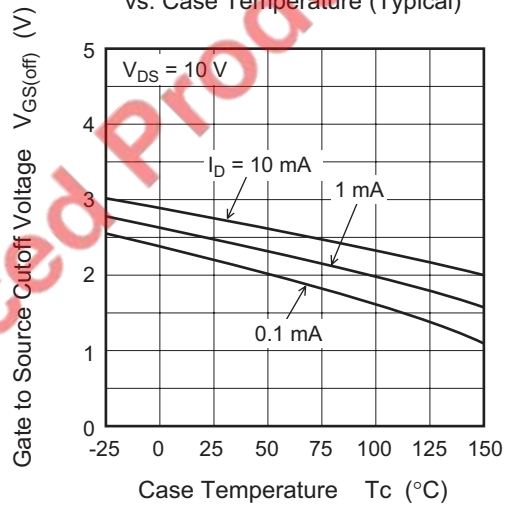
Dynamic Input Characteristics (Typical)



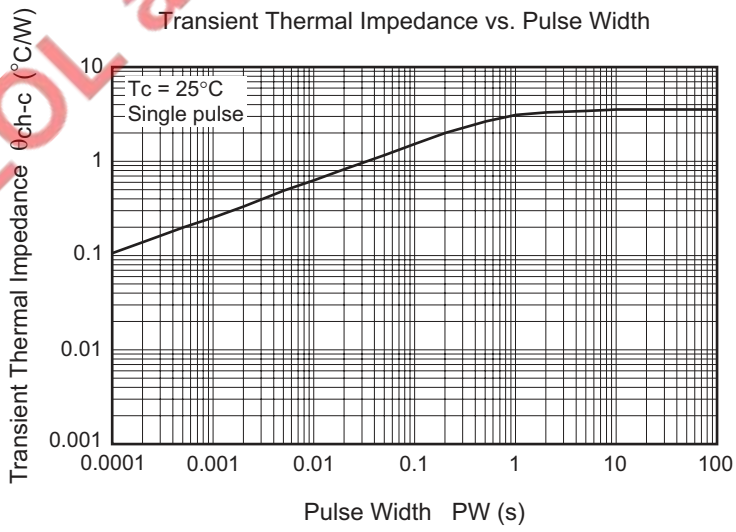
Reverse Drain Current vs.
Source to Drain Voltage (Typical)



Gate to Source Cutoff Voltage
vs. Case Temperature (Typical)



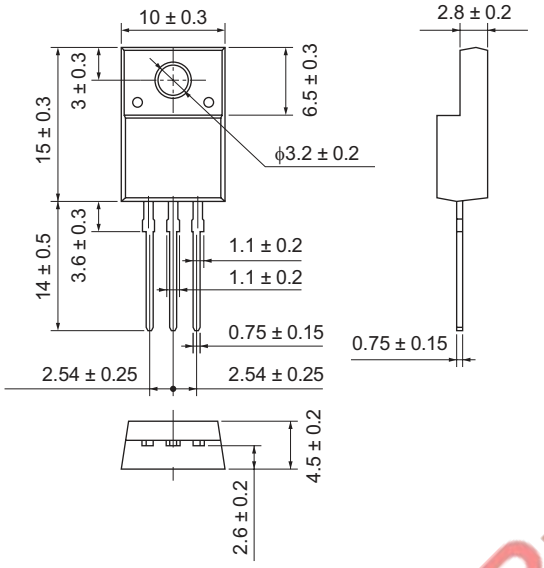
Transient Thermal Impedance vs. Pulse Width



Package Dimensions

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
TO-220FN	—	PRSS0003AB-A	—	2.0g

Unit: mm



Ordering Information

Part No.	Quantity	Shipping Container
H5N2512FN-E	1050 pcs	Box (Tube)

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